



**THE DATASHEET OF  
74AUP1T08GW-Q100H**



# 74AUP1T08-Q100

Low-power 2-input AND gate with voltage-level translator

Rev. 3.1 — 3 August 2023

Product data sheet

## 1. General description

The 74AUP1T08-Q100 provides the single 2-input AND function. This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 2.3 V to 3.6 V.

The 74AUP1T08-Q100 is designed for logic-level translation applications with input switching levels that accept 1.8 V low-voltage CMOS signals, while operating from either a single 2.5 V or 3.3 V supply voltage.

The wide supply voltage range ensures normal operation as battery voltage drops from 3.6 V to 2.3 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Schmitt trigger inputs make the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- Low static power consumption;  $I_{CC} = 1.5 \mu\text{A}$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial power-down mode operation
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

## 3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
<a href="#">74AUP1T08GW-Q100</a>	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	<a href="#">SOT353-1</a>

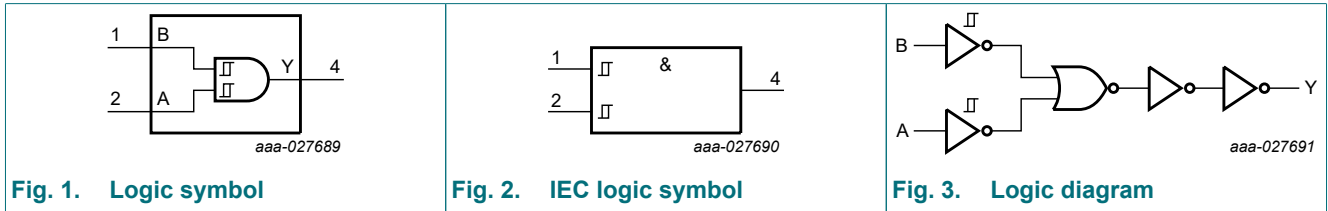
## 4. Marking

Table 2. Marking

Type number	Marking code[1]
74AUP1T08GW-Q100	5J

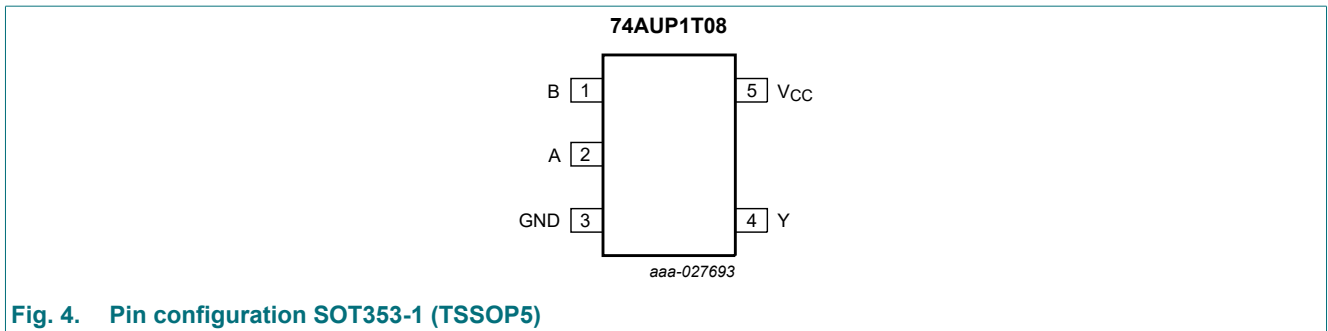
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram



## 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
B	1	data input
A	2	data input
GND	3	ground (0 V)
Y	4	data output
V <sub>CC</sub>	5	supply voltage

## 7. Functional description

**Table 4. Function table**

*H = HIGH voltage level; L = LOW voltage level.*

Input		Output
A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

## 8. Limiting values

**Table 5. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).*

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+4.6	V
$I_{IK}$	input clamping current	$V_I < 0$ V	-50	-	mA
$V_I$	input voltage		[1] -0.5	+4.6	V
$I_{OK}$	output clamping current	$V_O < 0$ V	-50	-	mA
$V_O$	output voltage	Active mode and Power-down mode	[1] -0.5	+4.6	V
$I_O$	output current	$V_O = 0$ V to $V_{CC}$	-	±20	mA
$I_{CC}$	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[2] -	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package:  $P_{tot}$  derates linearly with 3.3 mW/K above 74 °C.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		2.3	3.6	V
$V_I$	input voltage		0	3.6	V
$V_O$	output voltage	Active mode	0	$V_{CC}$	V
		Power-down mode; $V_{CC} = 0$ V	0	3.6	V
$T_{amb}$	ambient temperature		-40	+125	°C

## 10. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>T+</sub>	positive-going threshold voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	0.60	-	1.10	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.75	-	1.16	V
V <sub>T-</sub>	negative-going threshold voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	0.35	-	0.60	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.50	-	0.85	V
V <sub>H</sub>	hysteresis voltage	(V <sub>H</sub> = V <sub>T+</sub> - V <sub>T-</sub> )				
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.23	-	0.60	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.25	-	0.56	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	0.10	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.1	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.1	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	1.2	μA
C <sub>I</sub>	input capacitance	V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>	-	0.8	-	pF
C <sub>O</sub>	output capacitance	V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.7	-	pF

## Low-power 2-input AND gate with voltage-level translator

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>T+</sub>	positive-going threshold voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	0.60	-	1.10	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.75	-	1.19	V
V <sub>T-</sub>	negative-going threshold voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	0.35	-	0.60	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.50	-	0.85	V
V <sub>H</sub>	hysteresis voltage	(V <sub>H</sub> = V <sub>T+</sub> - V <sub>T-</sub> )				
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.10	-	0.60	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.15	-	0.56	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.5	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.5	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	1.5	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>CC</sub> = 2.3 V to 2.7 V; I <sub>O</sub> = 0 A [1]	-	-	0.6	μA
		V <sub>CC</sub> = 3.0 V to 3.6 V; I <sub>O</sub> = 0 A [2]	-	-	10	μA

## Low-power 2-input AND gate with voltage-level translator

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>T+</sub>	positive-going threshold voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	0.60	-	1.10	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.75	-	1.19	V
V <sub>T-</sub>	negative-going threshold voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	0.33	-	0.64	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.46	-	0.85	V
V <sub>H</sub>	hysteresis voltage	(V <sub>H</sub> = V <sub>T+</sub> - V <sub>T-</sub> )				
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.10	-	0.60	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.15	-	0.56	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.75	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	3.5	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>CC</sub> = 2.3 V to 2.7 V; I <sub>O</sub> = 0 A [1]	-	-	1.8	μA
		V <sub>CC</sub> = 3.0 V to 3.6 V; I <sub>O</sub> = 0 A [2]	-	-	18	μA

[1] One input at 0.3 V or 1.1 V, other input at V<sub>CC</sub> or GND.

[2] One input at 0.45 V or 1.2 V, other input at V<sub>CC</sub> or GND.

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
<b>V<sub>CC</sub> = 2.3 V to 2.7 V; V<sub>I</sub> = 1.65 V to 1.95 V</b>										
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 5 [2]								
		C <sub>L</sub> = 5 pF	2.0	3.3	5.2	0.5	6.8	0.5	7.5	ns
		C <sub>L</sub> = 10 pF	2.3	3.9	6.0	1.0	7.9	1.0	8.7	ns
		C <sub>L</sub> = 15 pF	2.7	4.4	6.6	1.0	8.7	1.0	9.6	ns
		C <sub>L</sub> = 30 pF	3.5	5.5	8.1	1.5	10.8	1.5	11.9	ns
<b>V<sub>CC</sub> = 2.3 V to 2.7 V; V<sub>I</sub> = 2.3 V to 2.7 V</b>										
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 5 [2]								
		C <sub>L</sub> = 5 pF	1.6	3.2	5.2	0.5	6.0	0.5	6.6	ns
		C <sub>L</sub> = 10 pF	1.9	3.8	6.0	1.0	7.1	1.0	7.9	ns
		C <sub>L</sub> = 15 pF	2.3	4.2	6.6	1.0	7.9	1.0	8.7	ns
		C <sub>L</sub> = 30 pF	3.1	5.4	8.1	1.5	10.0	1.5	11.0	ns
<b>V<sub>CC</sub> = 2.3 V to 2.7 V; V<sub>I</sub> = 3.0 V to 3.6 V</b>										
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 5 [2]								
		C <sub>L</sub> = 5 pF	1.2	2.9	4.7	0.5	5.5	0.5	6.1	ns
		C <sub>L</sub> = 10 pF	1.6	3.5	5.4	1.0	6.5	1.0	7.2	ns
		C <sub>L</sub> = 15 pF	1.9	4.0	6.1	1.0	7.4	1.0	8.2	ns
		C <sub>L</sub> = 30 pF	2.7	5.1	7.5	1.5	9.5	1.5	10.5	ns
<b>V<sub>CC</sub> = 3.0 V to 3.6 V; V<sub>I</sub> = 1.65 V to 1.95 V</b>										
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 5 [2]								
		C <sub>L</sub> = 5 pF	1.8	2.7	3.8	0.5	8.0	0.5	8.8	ns
		C <sub>L</sub> = 10 pF	2.3	3.3	4.5	1.0	8.5	1.0	9.4	ns
		C <sub>L</sub> = 15 pF	2.6	3.8	5.0	1.0	9.1	1.0	10.1	ns
		C <sub>L</sub> = 30 pF	3.4	4.9	6.5	1.5	9.8	1.5	10.8	ns
<b>V<sub>CC</sub> = 3.0 V to 3.6 V; V<sub>I</sub> = 2.3 V to 2.7 V</b>										
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 5 [2]								
		C <sub>L</sub> = 5 pF	1.5	2.6	4.0	0.5	5.3	0.5	5.9	ns
		C <sub>L</sub> = 10 pF	1.9	3.2	4.8	1.0	6.1	1.0	6.8	ns
		C <sub>L</sub> = 15 pF	2.1	3.7	5.4	1.0	6.8	1.0	7.5	ns
		C <sub>L</sub> = 30 pF	2.9	4.8	6.9	1.5	8.5	1.5	9.4	ns
<b>V<sub>CC</sub> = 3.0 V to 3.6 V; V<sub>I</sub> = 3.0 V to 3.6 V</b>										
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 5 [2]								
		C <sub>L</sub> = 5 pF	1.1	2.6	4.1	0.5	4.7	0.5	5.2	ns
		C <sub>L</sub> = 10 pF	1.5	3.2	4.8	1.0	5.7	1.0	6.3	ns
		C <sub>L</sub> = 15 pF	1.8	3.6	5.5	1.0	6.2	1.0	6.9	ns
		C <sub>L</sub> = 30 pF	2.5	4.8	7.0	1.5	7.8	1.5	8.6	ns

Low-power 2-input AND gate with voltage-level translator

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
<b>T<sub>amb</sub> = 25 °C</b>										
C <sub>PD</sub>	power dissipation capacitance	f <sub>i</sub> = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> [3]								
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	4	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	5	-	-	-	-	-	pF

- [1] All typical values are measured at nominal V<sub>CC</sub>.
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>
- [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = output load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of the outputs.

11.1. Waveform and test circuit

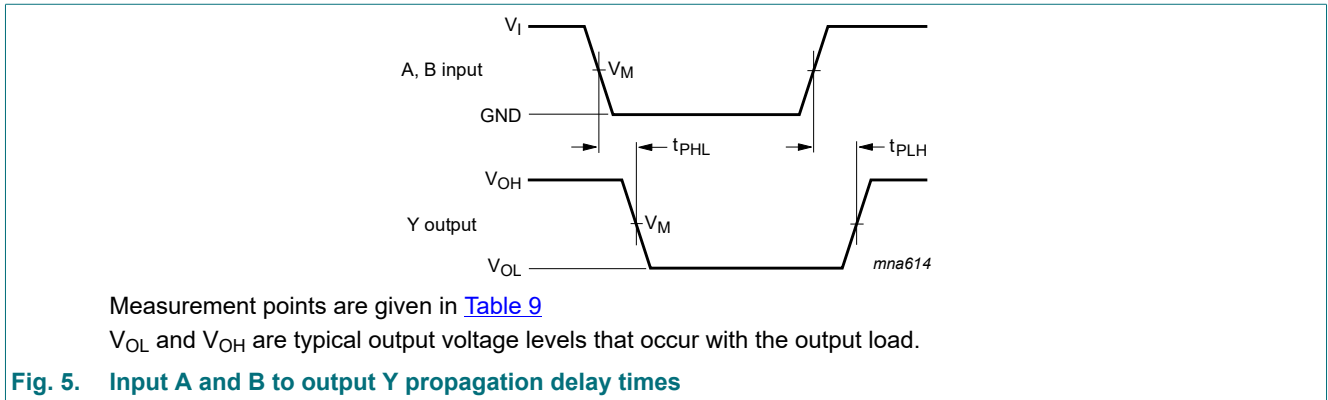
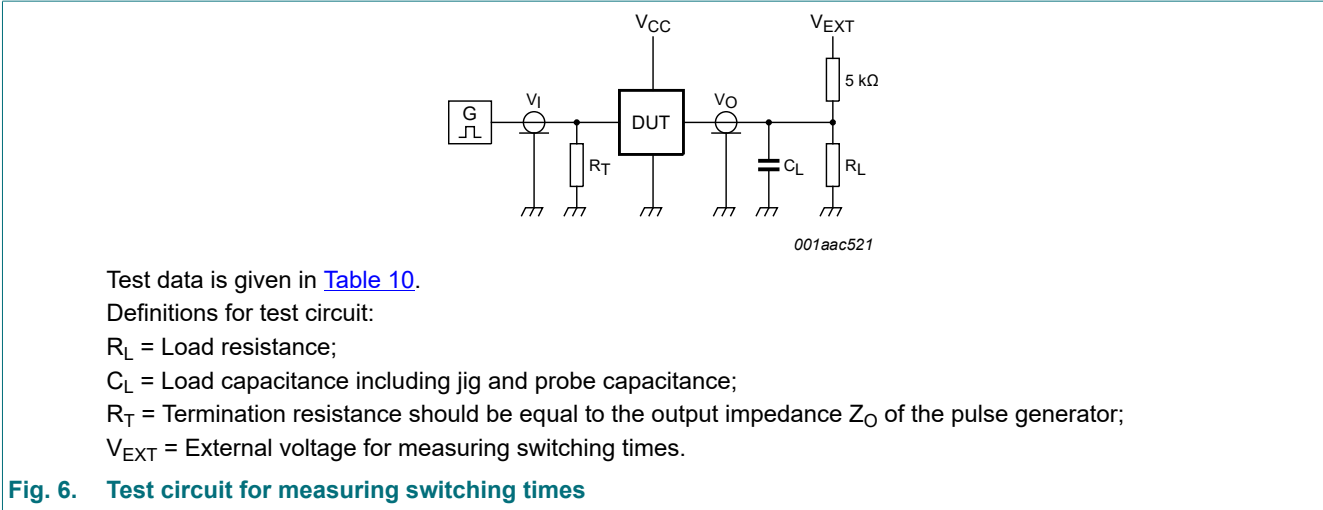


Table 9. Measurement points

Supply voltage	Output	Input		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>I</sub>	t <sub>r</sub> = t <sub>f</sub>
2.3 V to 3.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>I</sub>	1.65 V to 3.6 V	≤ 3.0 ns

Low-power 2-input AND gate with voltage-level translator



**Fig. 6. Test circuit for measuring switching times**

**Table 10. Test data**

Supply voltage	Load		$V_{EXT}$		
$V_{CC}$	$C_L$	$R_L$ [1]	$t_{PLH}$ , $t_{PHL}$	$t_{PZH}$ , $t_{PHZ}$	$t_{PZL}$ , $t_{PLZ}$
2.3 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ .  
 For measuring propagation delays, setup and hold times and pulse width  $R_L = 1 \text{ M}\Omega$ .

## 12. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



Fig. 7. Package outline SOT353-1 (TSSOP5)

## 13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model

## 14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1T08_Q100 v.3.1	20230803	Product data sheet	-	74AUP1T08_Q100 v.2
Modifications	<ul style="list-style-type: none"> <li><a href="#">Section 2</a>: ESD specification updated according to the latest JEDEC standard.</li> </ul>			
74AUP1T08_Q100 v.2	20220125	Product data sheet	-	74AUP1T08_Q100 v.1
Modifications	<ul style="list-style-type: none"> <li><a href="#">Fig. 7</a>: Package outline drawing for SOT353-1 (TSSOP5) has changed.</li> </ul>			
74AUP1T08_Q100 v.1	20210715	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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